Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.165 inches and 0.185 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

Between 0.190 inches and 0.210 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 7.0

emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

10.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset 2nd transistor

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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